

Thyristor High Voltage, Phase Control SCR, 30 A



| PRIMARY CHARACTERISTICS | | | | | |
|------------------------------------|-------------------|--|--|--|--|
| I _{T(AV)} | 20 A | | | | |
| V _{DRM} /V _{RRM} | 1600 V | | | | |
| V _{TM} | 1.3 V | | | | |
| I _{GT} | 45 mA | | | | |
| TJ | -40 °C to +125 °C | | | | |
| Package | TO-247AD 3L | | | | |
| Circuit configuration | Single SCR | | | | |

FEATURES

- Designed and qualified according to JEDEC® - JESD 47
- Flexible solution for reliable AC power rectification



- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-30TPS16L-M3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. AEC-Q101 qualified P/N available (VS-30TPS16LHM3).

| PARAMETER | TEST CONDITIONS | VALUES | UNITS |
|------------------------------------|------------------------------|-------------|-------|
| I _{T(AV)} | Sinusoidal waveform | 20 | Δ. |
| I _{RMS} | | 30 | A |
| V _{RRM} /V _{DRM} | | 1600 | V |
| I _{TSM} | | 300 | А |
| V _T | 20 A, T _J = 25 °C | 1.3 | V |
| dv/dt | | 500 | V/µs |
| di/dt | | 150 | A/µs |
| T _J | | -40 to +125 | °C |

| VOLTAGE RATINGS | | | | | | |
|-----------------|---|---|---|--|--|--|
| PART NUMBER | V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} /I _{DRM} AT 125 °C mA | | | |
| VS-30TPS16L-M3 | 1600 | 1700 | 10 | | | |



| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--|----------------------------------|--|---|--------|------------------|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS | |
| Maximum average on-state current | I _{T(AV)} | T _C = 95 °C, 180° conduction | half sine wave | 20 | | |
| Maximum RMS on-state current | I _{RMS} | | | 30 | Α | |
| Maximum peak, one-cycle, | I | 10 ms sine pulse, rated V _{RRM} | applied | 250 | ^ | |
| non-repetitive surge current | I _{TSM} | 10 ms sine pulse, no voltage | reapplied | 300 | | |
| Maximum I ² t for fusing | I ² t | 10 ms sine pulse, rated V _{RRM} | applied | 310 | A ² s | |
| Maximum i-t for fusing | 1-1 | 10 ms sine pulse, no voltage reapplied | | 442 | A-S | |
| Maximum I ² √t for fusing | I ² √t | t = 0.1 to 10 ms, no voltage reapplied | | 4420 | A²√s | |
| Maximum on-state voltage drop | V_{TM} | 20 A, T _J = 25 °C | | 1.3 | V | |
| On-state slope resistance | r _t | T _{.l} = 125 °C | | 12 | mΩ | |
| Threshold voltage | V _{T(TO)} | 1j = 125 C | | 1.0 | V | |
| Maximum reverse and direct leakage current | I _{RM} /I _{DM} | T _J = 25 °C | V _R = rated V _{RRM} /V _{DRM} | 0.5 | | |
| waximum reverse and direct leakage current | 'RM/ 'DM | T _J = 125 °C | VR - rated VRRM/ VDRM | 10 | mA | |
| Maximum holding current | I _H | Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C | | 150 | ША | |
| Maximum latching current | ΙL | Anode supply = 6 V, resistive load, T _J = 25 °C | | 200 | | |
| Maximum rate of rise of off-state voltage | dv/dt | $T_J = T_J$ maximum, linear to 80 % V_{DRM} , $R_g - k = open$ | | 500 | V/µs | |
| Maximum rate of rise of turned-on current | di/dt | | | 150 | A/μs | |

| TRIGGERING | | | | | | |
|---|--------------------|--|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum peak gate power | P _{GM} | | 8.0 | W | | |
| Maximum average gate power | P _{G(AV)} | | 2.0 | VV | | |
| Maximum peak positive gate current | +I _{GM} | | 1.5 | Α | | |
| Maximum peak negative gate voltage | -V _{GM} | | 10 | V | | |
| | I _{GT} | Anode supply = 6 V, resistive load, T _J = -10 °C | 60 | | | |
| Maximum required DC gate current to trigger | | Anode supply = 6 V, resistive load, $T_J = 25$ °C | 45 | mA | | |
| | | Anode supply = 6 V, resistive load, T _J = 125 °C | 20 | | | |
| Maximum required DC gate | | Anode supply = 6 V, resistive load, T _J = -10 °C | 2.5 | | | |
| Maximum required DC gate voltage to trigger | V _{GT} | Anode supply = 6 V, resistive load, $T_J = 25 ^{\circ}\text{C}$ | 2.0 | v | | |
| voltage to trigger | | Anode supply = 6 V, resistive load, T _J = 125 °C | 1.0 | V | | |
| Maximum DC gate voltage not to trigger | V_{GD} | T 405 % V waterd walking | 0.25 | | | |
| Maximum DC gate current not to trigger I _G | | T _J = 125 °C, V _{DRM} = rated value | 2.0 | mA | | |

| SWITCHING | | | | | | |
|-------------------------------|-----------------|--------------------------|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Typical turn-on time | t _{gt} | T _J = 25 °C | 0.9 | | | |
| Typical reverse recovery time | t _{rr} | T _{.l} = 125 °C | 4 | μs | | |
| Typical turn-off time | t _q | IJ = 125 C | 110 | | | |



| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | |
|---|---------|-----------------------------------|--------------------------------------|------------|------------|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | -40 to 125 | °C | |
| Maximum thermal resistance, junction to case | | R_{thJC} | DC operation | 0.8 | | |
| Maximum thermal resistance, junction to ambient | | R _{thJA} | DO Operation | 40 | °C/W | |
| Maximum thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.25 | | |
| Approximate weight | | | | 6 | g | |
| Approximate weight | | | | 0.21 | OZ. | |
| Mounting torque | minimum | | | 6 (5) | kgf · cm | |
| - Wounting torque | maximum | | | 12 (10) | (lbf · in) | |
| Marking device | | | Case style TO-247AD 3L | 30TP | S16L | |

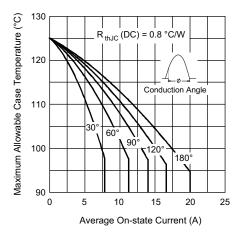


Fig. 1 - Current Rating Characteristics

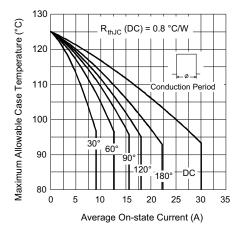


Fig. 2 - Current Rating Characteristics

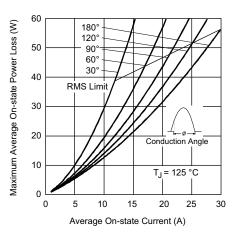


Fig. 3 - On-State Power Loss Characteristics

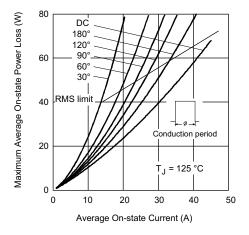


Fig. 4 - On-State Power Loss Characteristics



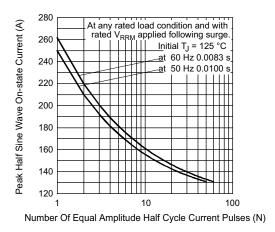


Fig. 5 - Maximum Non-Repetitive Surge Current

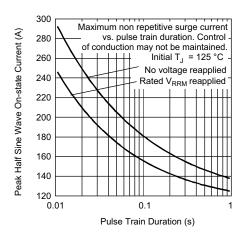


Fig. 6 - Maximum Non-Repetitive Surge Current

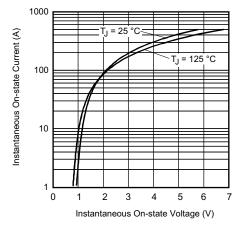


Fig. 7 - On-State Voltage Drop Characteristics

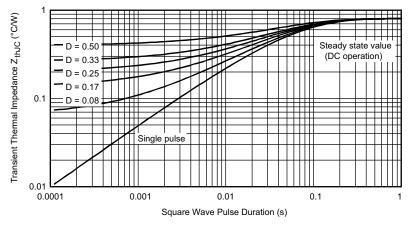


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



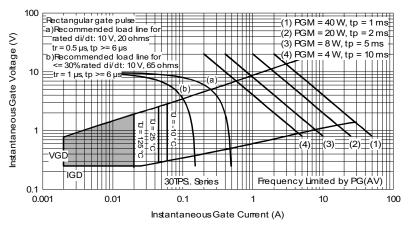
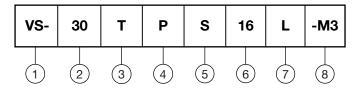


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 = 30 A)

3 - Circuit configuration:

T = thyristor

4 - Package:

P = TO-247

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage rating (16 = 1600 V)

7 - Package L = long lead

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

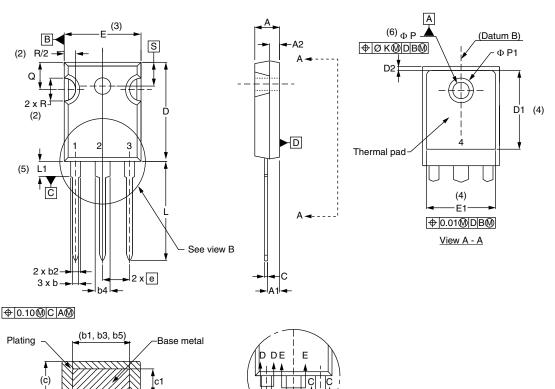
| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | |
| VS-30TPS16L-M3 | 25 | 500 | Antistatic plastic tubes | | | |

| LINKS TO RELATED DOCUMENTS | | | | |
|--|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?95626</u> | | | | |
| Part marking information | www.vishay.com/doc?95007 | | | |



TO-247AD 3L

DIMENSIONS in millimeters and inches



| (4) Section C - C, D - D, E - E | | | | | | | | |
|------------------------------------|--------|--------|-------|-------|-------|--|--|--|
| SYMBOL | MILLIN | IETERS | INC | HES | NOTES | | | |
| STIVIDUL | MIN. | MAX. | MIN. | MAX. | NOTES | | | |
| Α | 4.65 | 5.31 | 0.183 | 0.209 | | | | |
| A1 | 2.21 | 2.59 | 0.087 | 0.102 | | | | |
| A2 | 1.50 | 2.49 | 0.059 | 0.098 | | | | |
| b | 0.99 | 1.40 | 0.039 | 0.055 | | | | |

0.039

0.065

0.065

0.102

0.102

0.015

0.015

0.776

0.515

0.053

0.094

0.092

0.135

0.133

0.035

0.033

0.815

(h h2 h4)

| :5 | |
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View B

| SYMBOL | IVIILLIIV | ILILING | INOTIES | | NOTES |
|----------|-----------|----------|---------|-------|-------|
| STIVIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D2 | 0.51 | 1.30 | 0.020 | 0.051 | |
| E | 15.29 | 15.87 | 0.602 | 0.625 | 3 |
| E1 | 13.46 | - | 0.53 | - | |
| е | 5.46 | 5.46 BSC | | BSC | |
| ØΚ | 0.2 | 254 | 0.0 | 10 | |
| L | 19.81 | 20.32 | 0.780 | 0.800 | |
| L1 | 3.71 | 4.29 | 0.146 | 0.169 | |
| ØΡ | 3.56 | 3.66 | 0.14 | 0.144 | |
| Ø P1 | - | 6.98 | - | 0.275 | |
| Q | 5.31 | 5.69 | 0.209 | 0.224 | |
| R | 4.52 | 5.49 | 0.178 | 0.216 | |
| S | 5.51 BSC | | 0.217 | BSC | |
| • | • | | • | | • |

INCHES

MILLIMETERS

Notes

b1

b2

b3

b4

b5

С

с1

D

D1

(1) Dimensioning and tolerancing per ASME Y14.5M-1994

1.35

2.39

2.34

3.43

3.38

0.89

0.84

20.70

- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

3

- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1

0.99

1.65

1.65

2.59

2.59

0.38

0.38

19.71

13.08

- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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Vishay

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